

2N5322 2N5323

CASE 79-02, STYLE 1
TO-39 (TO-205AD)

SWITCHING TRANSISTOR

PNP SILICON

MAXIMUM RATINGS

Rating	Symbol	2N5322	2N5323	Unit
Collector-Emitter Voltage	V_{CE0}	75	50	Vdc
Collector-Base Voltage	V_{CBO}	100	75	Vdc
Emitter-Base Voltage	V_{EBO}	7.0	5.0	Vdc
Base Current	I_B	1.0		Adc
Collector Current — Continuous	I_C	2.0		Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	10	0.057	Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +200		$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	17.5	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Breakdown Voltage(1) ($I_C = 100 \text{ mAdc}, I_B = 0$)	$V_{(BR)CEO}$	75	—	Vdc
	2N5322	75	—	
	2N5323	50	—	
Collector Cutoff Current ($V_{CE} = 100 \text{ Vdc}, V_{BE} = 1.5 \text{ Vdc}$)	I_{CEX}	—	0.1	mAdc
($V_{CE} = 70 \text{ Vdc}, V_{BE} = 1.5 \text{ Vdc}, T_C = 150^\circ\text{C}$)	2N5322	—	5.0	
($V_{CE} = 75 \text{ Vdc}, V_{BE} = 1.5 \text{ Vdc}$)	2N5323	—	0.1	
($V_{CE} = 45 \text{ Vdc}, V_{BE} = 1.5 \text{ Vdc}, T_C = 150^\circ\text{C}$)		—	5.0	
Emitter Cutoff Current ($V_{BE} = 7.0 \text{ Vdc}, I_C = 0$)	I_{EBO}	—	0.1	mAdc
($V_{BE} = 5.0 \text{ Vdc}, I_C = 0$)	2N5322	—	0.1	
	2N5323	—	0.1	

ON CHARACTERISTICS(1)

DC Current Gain ($I_C = 500 \text{ mAdc}, V_{CE} = 4.0 \text{ Vdc}$)	h_{FE}	30	130	—
	2N5322	40	250	
($I_C = 1.0 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc}$)	2N5322	10	—	
Collector-Emitter Saturation Voltage ($I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc}$)	$V_{CE(sat)}$	—	0.7	Vdc
	2N5322	—	1.2	
	2N5323	—	1.2	
Base-Emitter On Voltage ($I_C = 500 \text{ mAdc}, V_{CE} = 4.0 \text{ Vdc}$)	$V_{BE(on)}$	—	1.1	Vdc
	2N5322	—	1.4	
	2N5323	—	1.4	

SMALL-SIGNAL CHARACTERISTICS

Small-Signal Current Gain ($I_C = 50 \text{ mAdc}, V_{CE} = 4.0 \text{ Vdc}, f = 10 \text{ MHz}$)	h_{fe}	5	—	—
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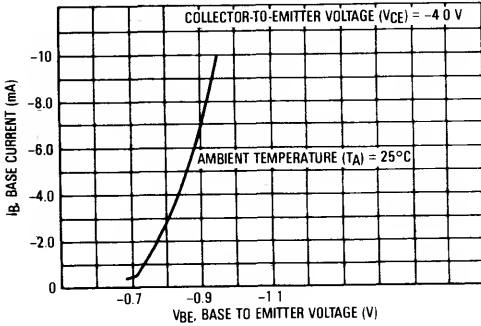
SWITCHING CHARACTERISTICS

Turn-On Time ($V_{CC} = 30 \text{ Vdc}, I_C = 500 \text{ mAdc}, I_{B1} = 50 \text{ mAdc}$)	t_{on}	—	100	ns
Turn-Off Time ($V_{CC} = 30 \text{ Vdc}, I_C = 500 \text{ mAdc}, I_{B1} = I_{B2} = 50 \text{ mAdc}$)	t_{off}	—	1000	ns

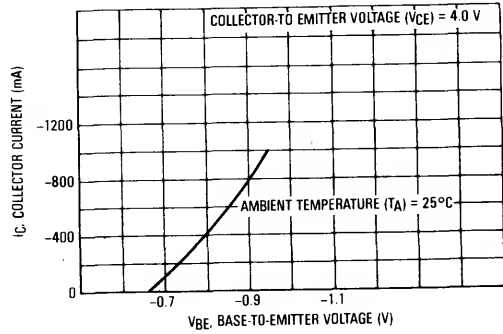
(1) Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2.0\%$.

2N5322, 2N5323

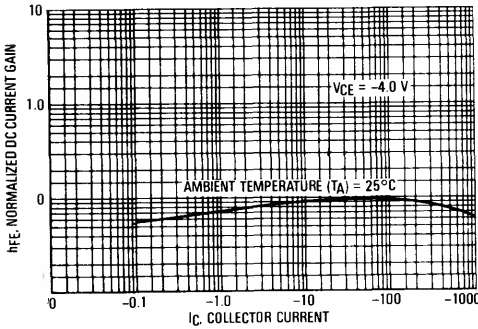
TYPICAL INPUT CHARACTERISTICS



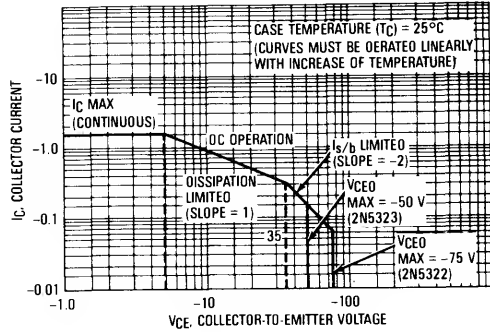
TYPICAL TRANSFER CHARACTERISTICS



CURRENT GAIN CHARACTERISTICS versus COLLECTOR-EMITTER VOLTAGE



MAXIMUM SAFE OPERATING AREAS (SOA)



2N5415, 2N5416

For Specifications, See 2N3439 Data.

2N5581

For Specifications, See 2N2218 Data.